## NSN 5961-00-768-0261

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View Online at https://aerobasegroup.com/nsn/5961-00-768-0261 **Inclosure Material:** Metal **Overall Length:** 0.540 inches **Overall Diameter:** 1.040 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.312 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 collector to base voltage/static/emitter open and 50.0 collector to emitter voltage, dc and 15.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** Between 1.00 amperes source cutoff current and 10.00 amperes source cutoff current **Power Rating Per Characteristic:** 150.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 2 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

No **Fiig:** 

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